# NSN 5962-01-359-5880

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 0.640 inches and 0.660 inches

# **Body Width:**

Between 0.540 inches and 0.550 inches

# **Body Height:**

Between 0.080 inches and 0.100 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Low power and high reliability and high performance and w/enable and monolithic and bidirectional and programmed and erasable

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Pin grid array

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

26 input

### **Current Rating Per Characteristic:**

60.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 7.0 volts power source

### Capitance Rating Per Characteristic:

6.00 input picofarads and 10.00 output picofarads

#### Memory Device Type:

Eeprom

#### Terminal Type And Quantity:

28 pin

# Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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